17.5V NPN MEDIUM POWER HIGH GAIN TRANSISTOR IN SOT223

Features

- BV_{CEO} > 17.5V
- BV_{CES} > 50V
- I_C = 5A High Continuous Collector Current
- I_{CM} = 20A Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)}$ <45mV @ 500mA
- R_{SAT} = 50mΩ @ 5A for a Low Equivalent On-Resistance
- h_{FE} Specified up to 20A for a High Gain Hold-Up
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

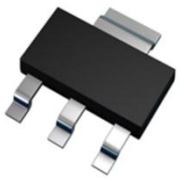
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.112 grams (Approximate)

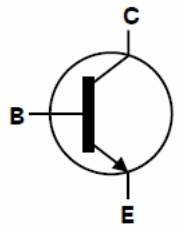
Applications

- Solenoid, Relay and Actuator Drivers
- DC Modules
- Motor Control

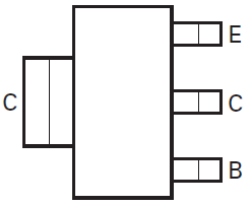
SOT223



Top View



Device Symbol



Top View
Pin-Out

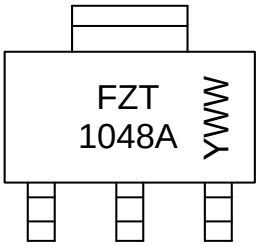
Ordering Information (Note 4)

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT1048ATA	FZT1048A	7	12	1,000

Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT223



FZT1048A = Product Type Marking Code
YWW = Date Code Marking
Y or $\overline{Y}$ = Last Digit of Year (ex: 8= 2018)
WW or $\overline{WW}$ = Week Code (01 to 53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	17.5	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	I_C	5	A
Peak Pulse Current	I_{CM}	20	A
Base Current	I_B	500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

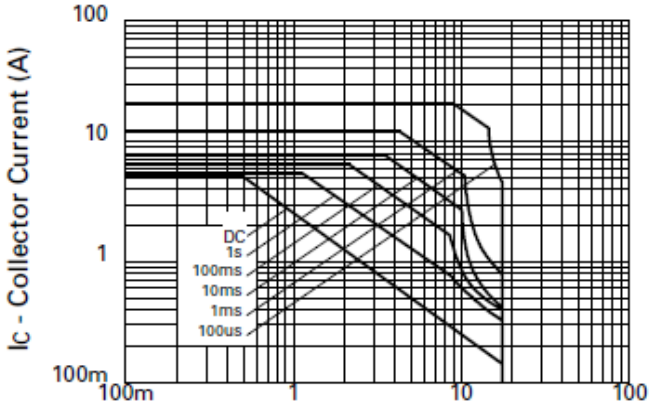
Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	3.0	W
	(Note 6)		2.0	
	(Note 7)		1.6	
	(Note 8)		1.2	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	41.7	°C/W
	(Note 6)		62.5	
	(Note 7)		78.1	
	(Note 8)		104	
Thermal Resistance Junction to Lead	(Note 9)	$R_{\theta JL}$	10.9	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 10)

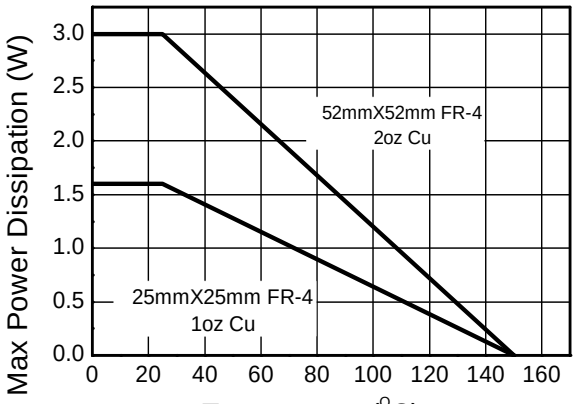
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Same as note (5), except the device is mounted on 25mm x 25mm 2oz copper.
7. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
8. Same as note (5), except the device is mounted on minimum recommended pad layout.
9. Thermal resistance from junction to solder-point (at the end of the collector lead).
10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

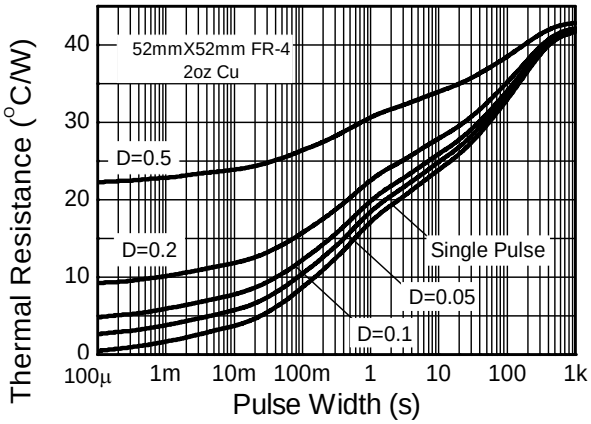
Thermal Characteristics and Derating Information



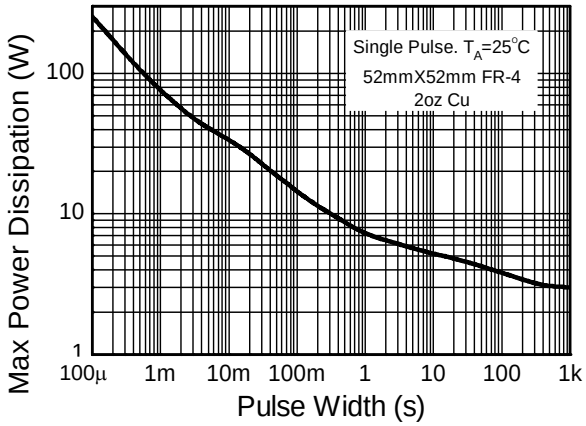
Safe Operating Area



Derating Curve



Transient Thermal Impedance



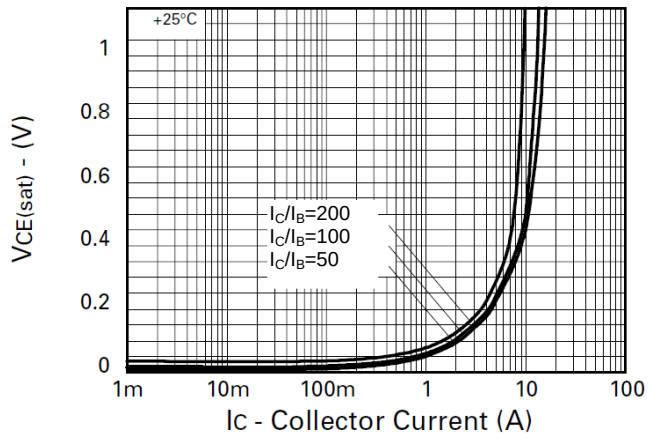
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

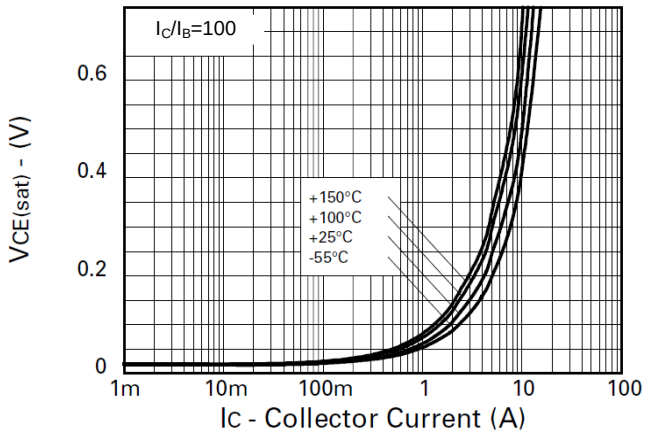
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	50	85	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage	BV_{CES}	50	85	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage	BV_{CEV}	50	85	—	V	I_C = 100µA, V_{EB} = 1V
Collector-Emitter Breakdown Voltage (Note 11)	BV_{CEO}	17.5	24	—	V	I_C = 10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	7	8.7	—	V	I_E = 100µA
Collector Cut-off Current	I_{CBO}	—	0.3	10	nA	V_{CB} = 35V
Collector Cut-off Current	I_{CES}	—	0.3	10	nA	V_{CB} = 35V
Emitter Cut-off Current	I_{EBO}	—	0.3	10	nA	V_{EB} = 4V
Collector-Emitter Saturation Voltage (Note 11)	$V_{CE(sat)}$	—	27	45	mV	I_C = 500mA, I_B = 10mA
		—	55	75		I_C = 1A, I_B = 10mA
		—	155	210		I_C = 3A, I_B = 15mA
		—	250	350		I_C = 5A, I_B = 25mA
Base-Emitter Saturation Voltage (Note 11)	$V_{BE(sat)}$	—	920	1,000	mV	I_C = 5A, I_B = 25mA
Base-Emitter Turn-On Voltage (Note 11)	$V_{BE(on)}$	—	880	970	mV	I_C = 5A, V_{CE} = 2V
DC Current Gain (Note 11)	h_{FE}	280	440	—	—	I_C = 10mA, V_{CE} = 2V
		300	450	—		I_C = 0.5A, V_{CE} = 2V
		300	450	1,200		I_C = 1A, V_{CE} = 2V
		180	300	—		I_C = 5A, V_{CE} = 2V
		50	80	—		I_C = 20A, V_{CE} = 2V
Output Capacitance	C_{obo}	—	60	80	pF	V_{CB} = 10V, f = 1MHz
Current Gain-Bandwidth Product	f_T	—	150	—	MHz	V_{CE} = 10V, I_C = 50mA, f = 50MHz
Switching Times	t_{on}	—	120	—	ns	I_C = 4A, V_{CC} = 10V, I_{B1} = -I_{B2} = 40mA
	t_{off}	—	310	—		

Note: 11. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2.

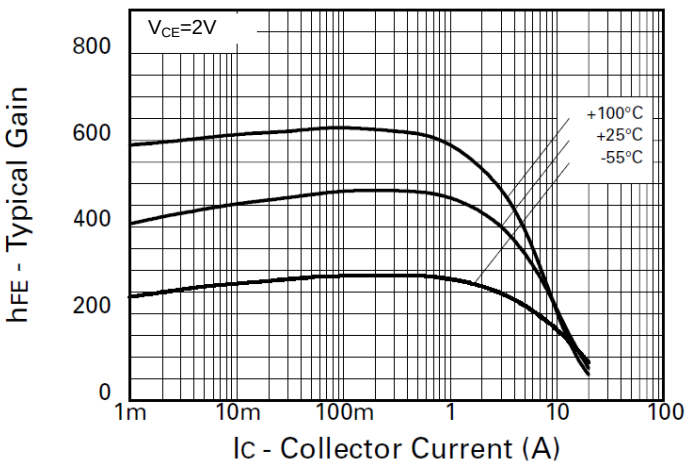
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



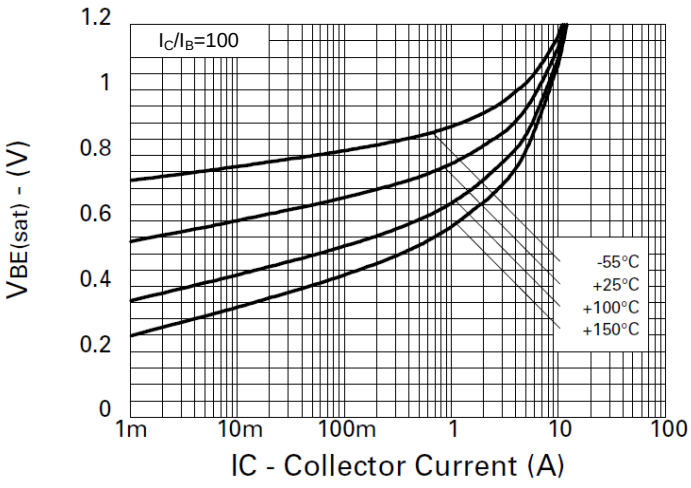
$V_{CE(sat)}$ v I_C



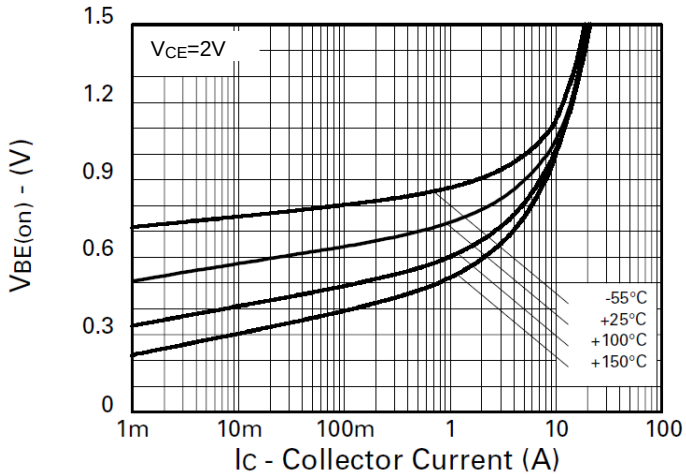
$V_{CE(sat)}$ v I_C



h_{FE} v I_C



$V_{BE(sat)}$ v I_C

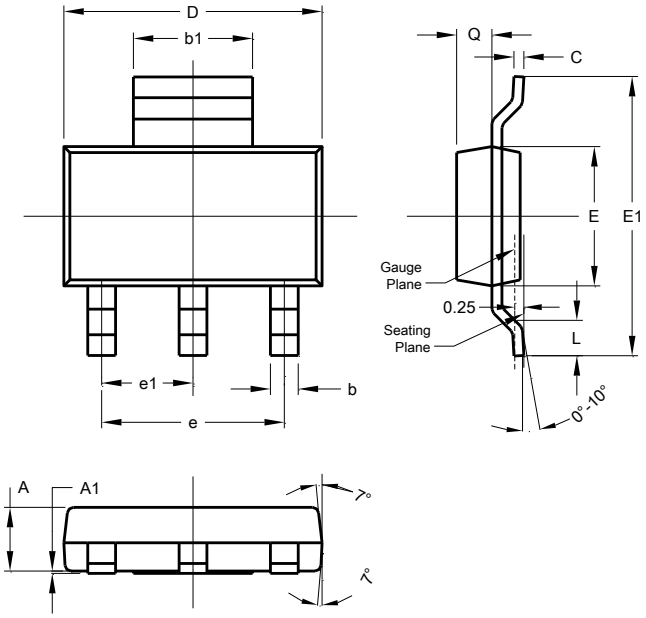


$V_{BE(on)}$ v I_C

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223

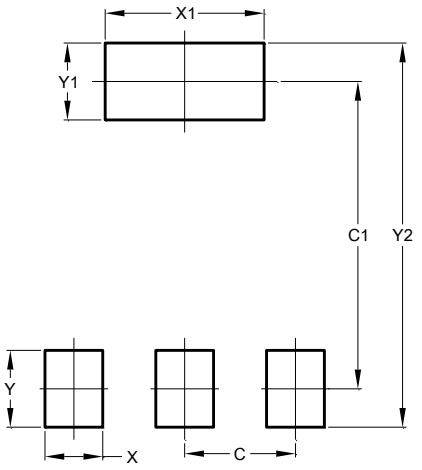


SOT223			
Dim	**Min**	**Max**	**Typ**
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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